

TYN16-800RT

SCR Rev. 1 — 2 July 2012

Product data sheet

1. Product profile

1.1 General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 (TO-220AB) plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ($T_{i(max)} = 150$ °C).

1.2 Features and benefits

- High junction operating temperature capability
- High thermal cycling performance
- High voltage capability

1.3 Applications

- Ignition circuits
- Motor control

- Planar passivated for voltage ruggedness and reliability
- Very high current surge capability
- Protection circuits e.g. SMPS inrush current
- Voltage regulation

1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off-state voltage)	-	-	800	V
V _{RRM}	repetitive peak reverse voltage		-	-	800	V
I _{TSM}	non-repetitive peak on-state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	-	210	А
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	-	231	А
Tj	junction temperature		-	-	150	°C
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 134 °C; see <u>Figure 3</u>	-	-	10.2	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 134 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	16	А



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Table 1.	Quick reference data continue	d				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; see <u>Figure 7</u>	-	4.5	25	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	300	-	-	V/µs

2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	А	anode	mb	А Н К
3	G	gate		G sym037
mb	A	mounting base; connected to anode		

TO-220AB (SOT78)

Ordering information 3.

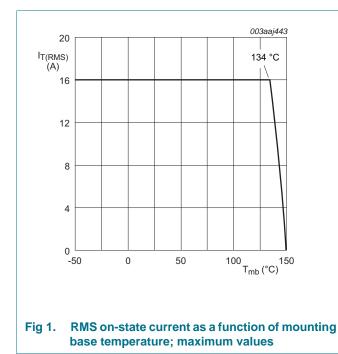
Table 3. Orderin	information		
Type number	Package		
	Name	Description	Version
TYN16-800RT	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

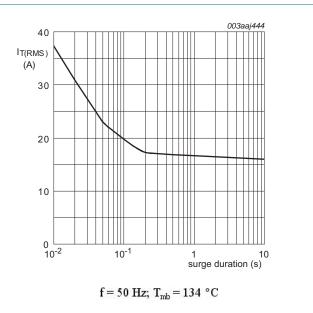
4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
V _{RRM}	repetitive peak reverse voltage		-	800	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 134 °C; see <u>Figure 3</u>	-	10.2	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 134 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	16	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	210	А
		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 8.3 \text{ ms}$	-	231	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	220.5	A ² s
dl _T /dt	rate of rise of on-state current	$I_T = 40 \text{ A}; I_G = 200 \text{ mA}; \text{ d}I_G/\text{d}t = 200 \text{ mA}/\mu\text{s}$	-	50	A/µs
I _{GM}	peak gate current		-	5	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	20	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

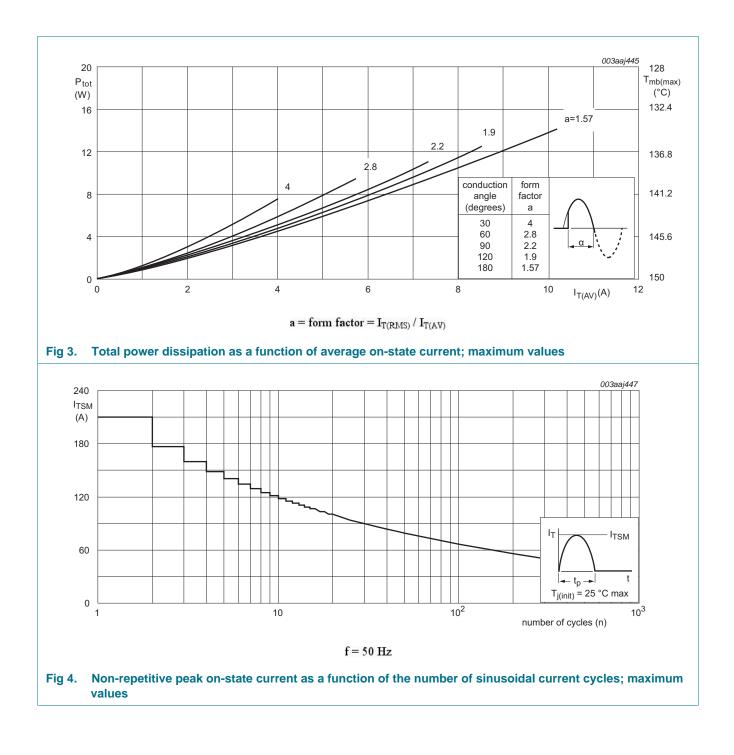






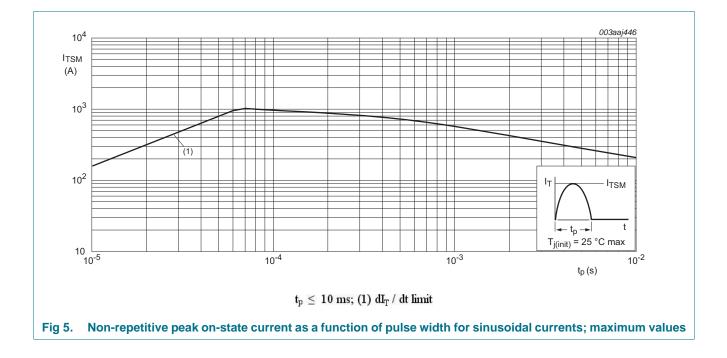
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5. Thermal characteristics

Table J.	mermai characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 6	-	-	1.1	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

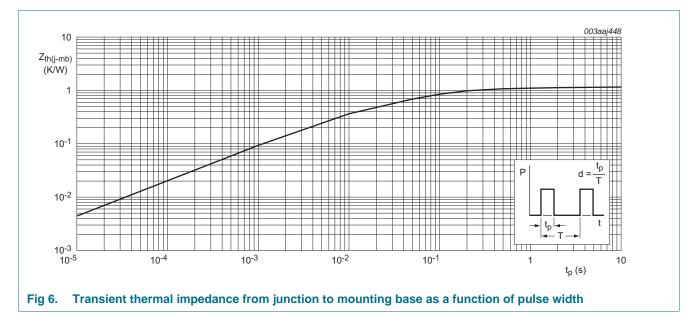
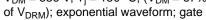
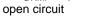


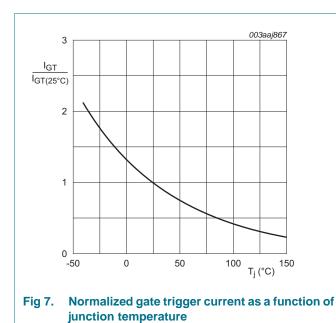
Table 5. Thermal characteristics

6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; see <u>Figure 7</u>	-	4.5	25	mA
IL	latching current	V_D = 12 V; I_G = 0.1 A; T_j = 25 °C; see <u>Figure 8</u>	-	21	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; see <u>Figure 9</u>	-	16	40	mA
V _T	on-state voltage	I _T = 32 A; T _j = 25 °C; see <u>Figure 10</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; see <u>Figure 11</u>	-	0.7	1.3	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; see <u>Figure 11</u>	0.2	0.4	-	V
I _D	off-state current	$V_D = 800 \text{ V}; \text{ T}_j = 150 \text{ °C}$	-	0.2	1	mA
I _R	reverse current	T _j = 150 °C; V _R = 800 V	-	0.2	1	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 536 V; T _i = 150 °C; (V _{DM} = 67%	300	-	-	V/µs







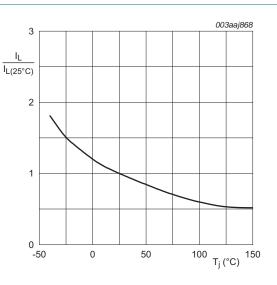
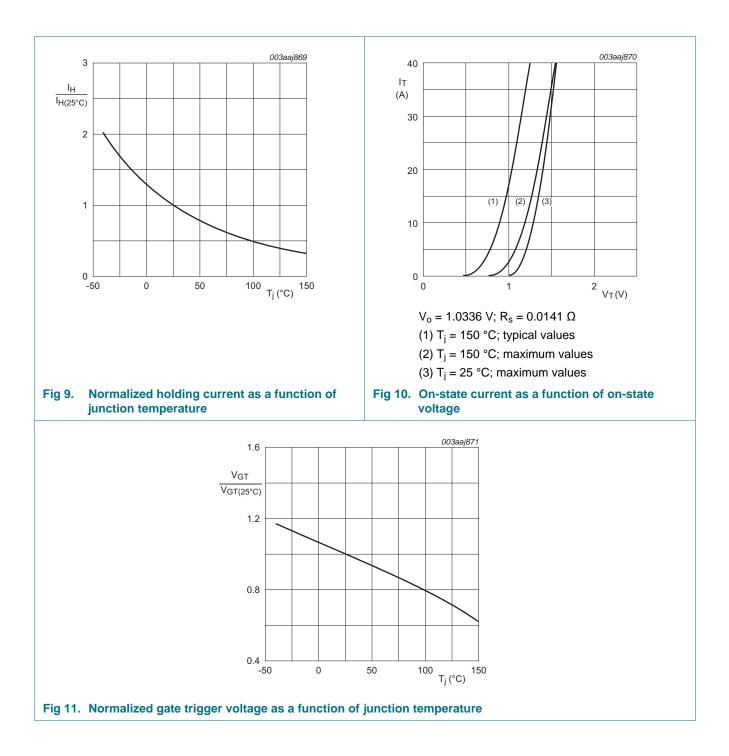


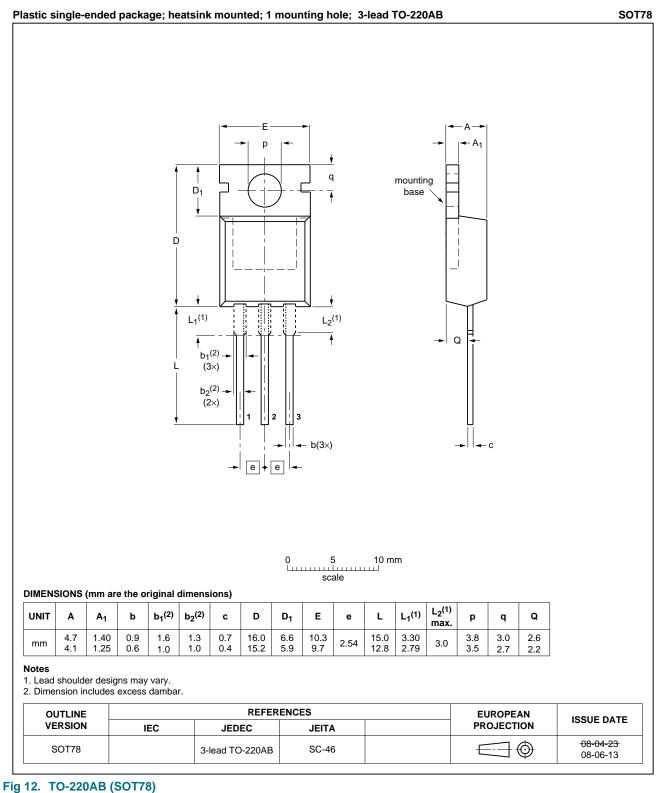
Fig 8. Normalized latching current as a function of junction temperature

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Package outline 7.



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8. Revision history

Table 7. Re	Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
TYN16-800RT	v.1 20120702	Product data sheet	-	-			

Legal information 9.

9.1 Data sheet status

Document status[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions'

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